Features

- **Temperature and Voltage Compensated Frequency**
- **Warning Indication of Lamp Failure by Means of Frequency Doubling only in Direction Mode**
- **Voltage Dependence of the Car Indicator Lamps also Compensated for Lamp Failure**
- **Relay Output with High Current-carrying Capacity and Low Saturation Voltage**
- **Load-dump Protection**
- **Minimum Lamp Load for Flasher Operation ≥ 1 W**
- **Low Susceptibility to EMI**
- **Extremely Low Standby Current of 10 µA**
- **Protection According to ISO/TR 7637/1 Level 4 with External Capacitor (C_2)**

Description

The U6432B is an advanced automotive flasher IC which provides low standby current. Its basic function is equal to Atmel's flasher IC U6043B but low current consumption and frequency doubling disabling make outstanding differences.

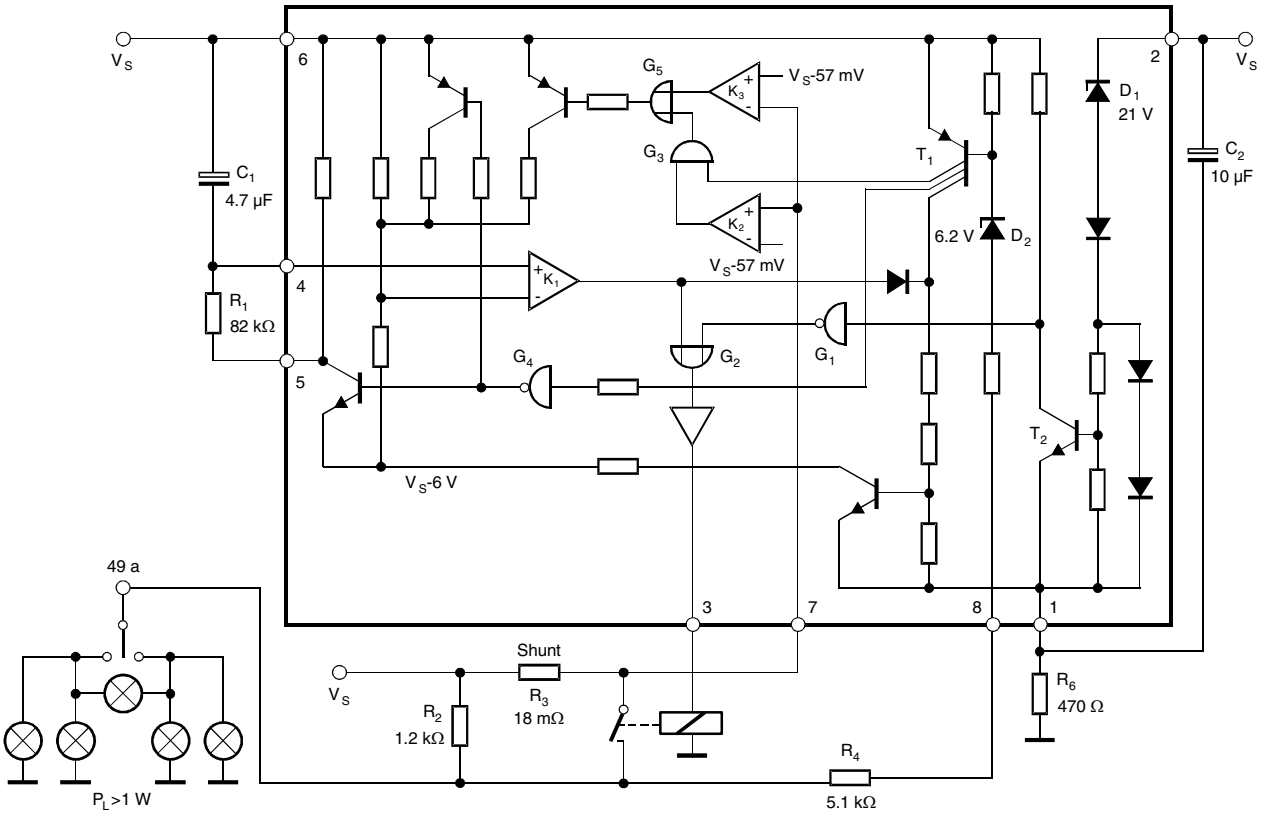
Low-power Flasher IC with 18-mΩ Shunt

U6432B

4725A–AUTO–06/03

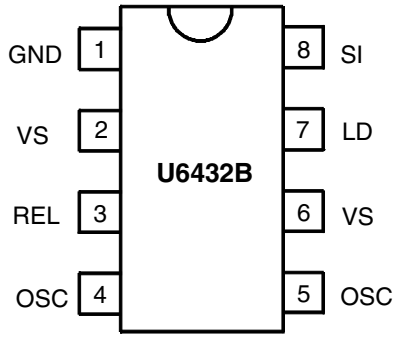
Block Diagram

Figure 1. Car Flasher Application



Pin Configuration

Figure 2. Pinning



Pin Description

Pin	Symbol	Function
1	GND	IC ground
2	VS	Supply voltage
3	REL	Relay driver
4	OSC	Oscillator
5	OSC	Oscillator
6	VS	Supply voltage
7	LD	Lamp failure detection
8	SI	Start input (49a)

Functional Description

Pin 1, GND

The U6432B is protected against damage in case of battery reversal via resistor R_4 to ground (-31). An integrated protection circuit together with external resistances R_2 and R_4 limits the current pulses in the IC.

Pin 2, Supply Voltage, V_S power

The arrangement of the supply connections to Pin 2 (and 6) must be so as to ensure that on the connection printed circuit board (PCB), the resistance of V_S to Pin 6 is lower than that to Pin 2.

Pin 3, Relay Control Output (Driver)

The relay control output is a high-side driver with a low saturation voltage. It is capable of driving a typical automotive relay with a minimum coil resistance of 60 Ω.

Pin 4 and 5, Oscillator

The flashing frequency, f_1, is determined by the R_1C_1 components as given by the formula below (see Figure 1):

$$f_1 \approx \frac{1}{R_1 \times C_1 \times 1.5} Hz$$

where $C_1 \leq 47$ µF, R_1 = 6.8 kΩ to 510 kΩ

In case of a lamp outage (see Pin 7) the oscillator frequency is switched to the lamp outage frequency f_2 with $f_2 \approx 2.2 \times f_1$.

Duty cycle in normal flashing mode: 50%
Duty cycle in lamp outage mode: 40% (bright phase)

Pin 6, Supply Voltage, Sense

For accurate monitoring via the shunt resistor, a minimized layer resistance from point V_S/shunt to Pin 6 is recommended.

Pin 7

Control Signal Threshold (49 mV Comparator)

The detection point for lamp failure can be calculated from the control signal threshold, typically 49 mV with V_S = 12 V. With a measuring resistance of R_3 = 18 mΩ, the frequency change-over is reached at a lamp load of 21 W + 11.4 W. The variation of the control signal threshold supply voltage takes into account the PTC characteristic of filament lamps.

Control Signal Threshold 2 (15-mV Comparator)

A voltage drop at the shunt resistor R_3 between 49 mV and 15 mV lets the flasher work in frequency doubling mode.

If the voltage drop decreases to a value below V_{R3MAX} = 15 mV, frequency doubling is disabled.

This can be achieved either with a switch which by-passes the shunt resistor (e.g., a special hazard warning switch) or with a small lamp load.

Flasher operation starts with a lamp load of $P_L \geq 1$ W.

Pin 8, Start Input

Start condition for flashing:

- Voltage at Pin 8 (see Figure 1)
- $V_8 \leq V_S - (V_{BE(T1)} + V_{Z(D2)})$

Condition for standby:

The resistor R_2 betwen V_S and Pin 8 provides an extremly low standby current ($I_S \leq 10$ µA). The leakage current depends on the pull-up resistor R_2 according to the following formula:

$I_{Leak} \approx (V_{BE(T1)} + V_{Z(D2)})/R_2$

Application Hint

In order to achieve a high-level immunity against "electrical interference by conduction and coupling" according to ISO/TR 7637/1 test level 4, an electrolythic capacitor C_2 = 10 µF (25 V) between Pin 1 and 2 – mounted close to the IC – is highly recommended.

Absolute Maximum Ratings

Reference point Pin 1

Parameters		Symbol	Value	Unit
Supply voltage	Pin 2 and 6	V_S	18	V
Surge Forward Current				
t_P = 0.1 ms	Pin 2 and 6	I_{FSM}	1.5	A
t_P = 300 ms	Pin 2 and 6	I_{FSM}	1.0	A
t_P = 300 ms	Pin 8	I_{FSM}	30	mA
Output current	Pin 3	I_O	0.3	A
Power Dissipation				
T_{amb} = 95°C	DIP 8	P_{tot}	420	mW
	SO8	P_{tot}	340	mW
T_{amb} = 60°C	DIP 8	P_{tot}	690	mW
	SO8	P_{tot}	560	mW
Junction temperature		T_J	150	°C
Ambient temperature range		T_{amb}	-40 to +105	°C
Storage temperature range		T_{stg}	-55 to +150	°C

Electrical Characteristics

T_{amb} = 25°C; typical values under normal operation in application circuit Figure 1, V_S = 12 V (Pins 2 and 6); reference point ground (-31), unless otherwise specified.

Parameters	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Supply voltage range	Pin 2 and 6	V_S	9		16.5	V
Supply current, dark phase	Pins 2 and 6	I_S		4.5	8	mA
Supply current, stand-by	Pins 2 and 6	I_S			10	mA
Supply current, bright phase	Pins 2 and 6	I_S		7.0	11	mA
Relay output, saturation voltage	I_O = 150 mA V_S = 9 V, Pin 3	V_O			1.0	V
Relay output reverse current	Pin 3	I_O			0.1	mA
Relay coil resistance		R_L	60			Ω
Start delay	First bright phase	t_{on}			10	ms
Frequency determining resistor		R_1	6.8		510	kΩ
Frequency determining capacitor		C_1			47	µF
Frequency tolerance	Normal flashing, basic frequency f_1 not including the tolerances of the external components R_1 and C_1	Δf_1	-5		+5	%
Bright period	Basic frequency f_1 V_S = 9 to 15 V	Δf_1	47		53	%
Bright period	Control frequency f_2 V_S = 9 to 15 V	Δf_2	37		45	%
Frequency increase	Lamp failure, V_S = 9 to 15 V	f_2	2.15 × f_1		2.3 × f_1	Hz
Control signal threshold 1	V_S = 15 V V_S = 9 V V_S = 12 V, Pin 7	V_{R3}	50 43 47	53 45 49	57 47 51	mV
Control signal threshold 2		V_{R3}			15	mV
Lamp load		P_L	1			W

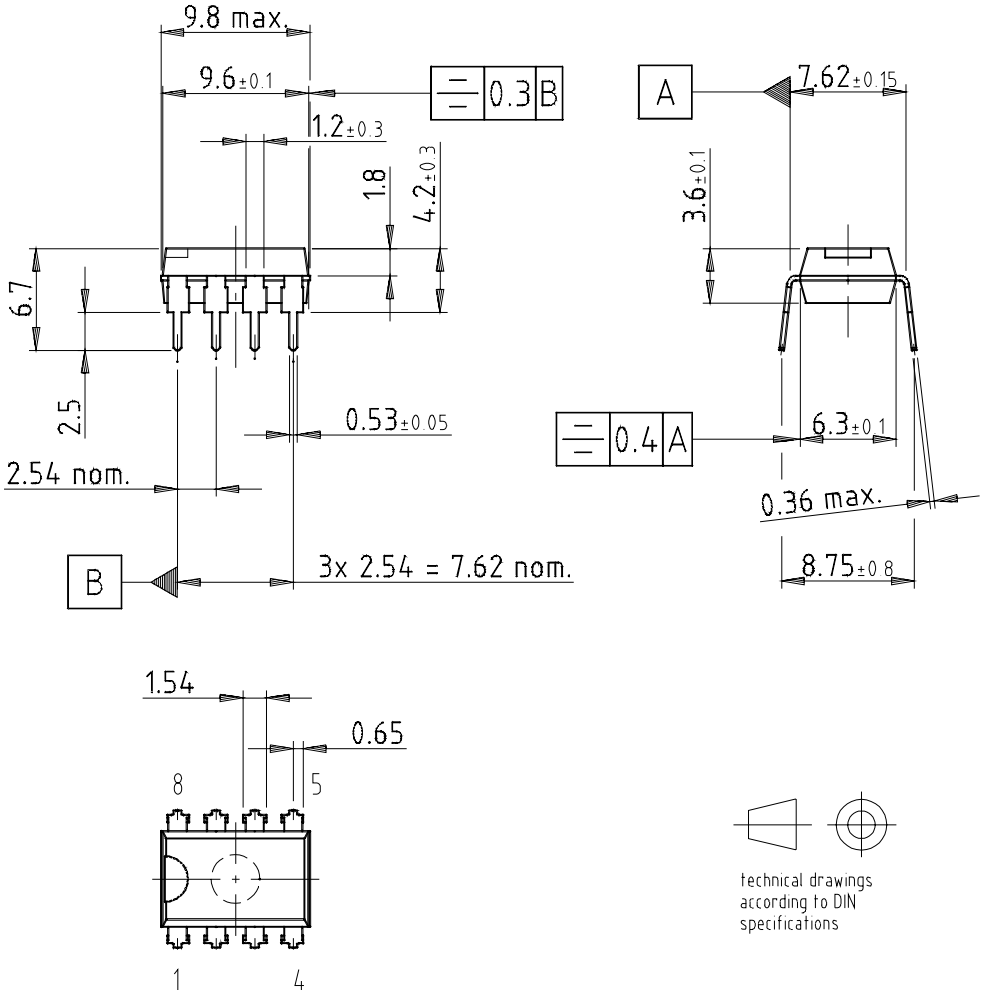
Ordering Information

Extended Type Number	Package	Remarks
U6432B	DIP8	–
U6432B-FP	SO8	–

Package Information

DIP8

Package: DIP 8
Dimensions in mm

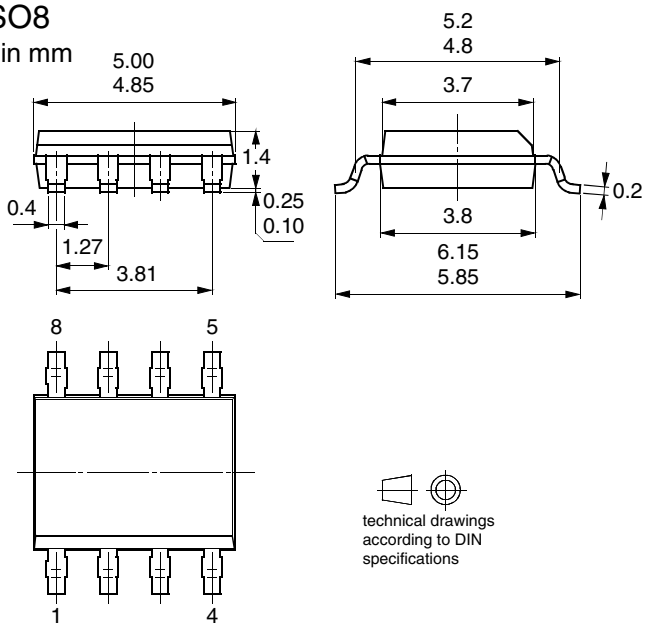


Drawing-No.: 6.543-5040.01-4
Issue: 1; 16.01.02

SO8

Package SO8

Dimensions in mm



technical drawings
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